

GPA025A120MN-ND

GPA025A120MN-ND Information

Source have		GPA025A120MN-ND Global Power Technologies Group Discrete Semiconductor Products Transistors - IGBTs - Single IGBT 1200V 50A 312W TO3PN TO-3 For the pricing/inventory/lead time, please contact	
For Reference	ce Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



GPA025A120MN-ND Specifications

Manufacturer Part Number	GPA025A120MN-ND
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-3
Series	-
IGBT Type	NPT and Trench
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	50A
Current - Collector Pulsed (Icm)	75A
Vce(on) (Max) @ Vge, Ic	2.5V @ 15V, 25A
Power - Max	312W
Switching Energy	4.15mJ (on), 870µJ (off)
Input Type	Standard
Gate Charge	350nC
Td (on/off) @ 25°C	57ns/240ns
Test Condition	600V, 25A, 10 Ohm, 15V
Reverse Recovery Time (trr)	480ns
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-3
Supplier Device Package	TO-3PN
	Report errors?

GPA025A120MN-ND Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

GPA025A120MN-ND Payment Methods





If you have any question about GPA025A120MN-ND, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com